

09/111,516

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	466	438/460	USPAT; EPO; JPO	2001/12/30 16:25
2	BRS	L2	36818	semiconductor adj material	USPAT; EPO; JPO	2001/12/30 16:26
3	BRS	L3	208795	thin adj film	USPAT; EPO; JPO	2001/12/30 16:29
4	BRS	L4	529	microcavities	USPAT; EPO; JPO	2001/12/30 16:34
5	BRS	L5	423140	ions	USPAT; EPO; JPO	2001/12/30 16:34
6	BRS	L6	312080	bonding	USPAT; EPO; JPO	2001/12/30 16:34
7	BRS	L7	32976	thermal adj energy	USPAT; EPO; JPO	2001/12/30 16:35
8	BRS	L8	1	2 and 3 and 4 and 5 and 6 and 7 6,225,192	USPAT; EPO; JPO	2001/12/30 16:35
9	BRS	L9	1	1 and 2 and 3 and 4 11	USPAT; EPO; JPO	2001/12/30 16:36
10	BRS	L10	35	2 and 3 and 4	USPAT; EPO; JPO	2001/12/30 16:36
11	BRS	L11	1239	5 and 6 and 7	USPAT; EPO; JPO	2001/12/30 16:36
12	BRS	L12	125	5 and 6 and 7 and 2	USPAT; EPO; JPO	2001/12/30 16:36

	Type	L #	Hits	Search Text	DBs	Time Stamp
13	BRS	L13	85	5 and 6 and 7 and 2 and 3	USPAT; EPO; JPO	2001/12/30 16:37
14	BRS	L14	3	5 and 6 and 7 and 1 and 2 and 3	USPAT; EPO; JPO	2001/12/30 16:37

- 6,225,192

- 6,159,825

= 5,897,330

L10

- 6,266,357

* 6,225,192

- 6,103,597

* 6,020,252